

T-41-73

GP1L53 Compact Type Photointerrupter

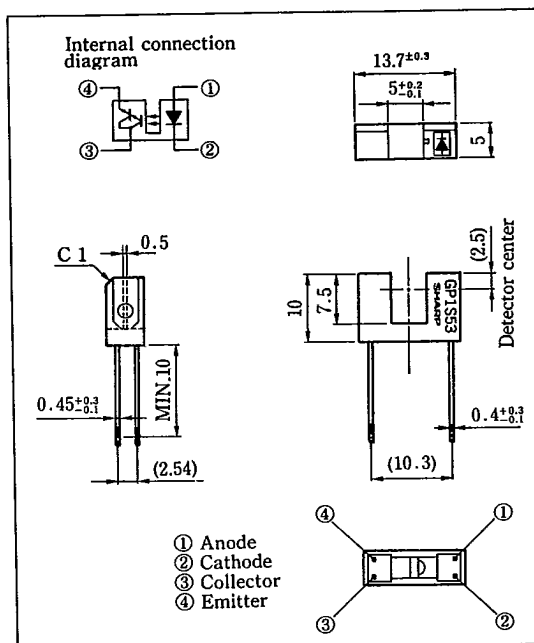
■ Features

1. Compact type
2. High sensing accuracy (Slit width: 0.5mm)
3. High current transfer ratio (CTR: MIN. 30% at $I_F = 1\text{mA}$)
4. PWB direct mounting type

■ Applications

1. OA equipment such as FDDs, printers, facsimiles, etc.
2. VCRs
3. Optoelectronic switches

■ Outline Dimensions (Unit : mm)



■ Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	*1 Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	75	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	40	mA
	Collector power dissipation	P_C	75	mW
	Operating temperature	T_{opr}	-25 ~ +85	°C
	Storage temperature	T_{stg}	-40 ~ +100	°C
	*2 Soldering temperature	T_{sol}	260	°C

*1 Pulse width ≤ 100μs, Duty ratio = 0.01

*2 For 5 seconds

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■ Electro-optical Characteristics

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(Ta=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F=20\text{mA}$	—	1.25	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM}=0.5\text{A}$	—	3	4	V
	Reverse Current	I_R	$V_R=3\text{V}$	—	—	10	μA
Output	Collector dark current	I_{CEO}	$V_{CE}=10\text{V}$	—	—	10^{-6}	A
	Current transfer ratio	CTR	$I_F=1\text{mA}, V_{CE}=2\text{V}$	30	—	2,000	%
Transfer characteristics	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F=2\text{mA}, I_C=0.3\text{mA}$	—	—	1.0	V
	Response time (Rise)	t_r	$V_{CE}=2\text{V}, I_C=2\text{mA}$	—	130	400	μs
	Response time (Fall)	t_f	$R_L=100\Omega$	—	100	350	μs

Fig. 1 Forward Current vs. Ambient Temperature

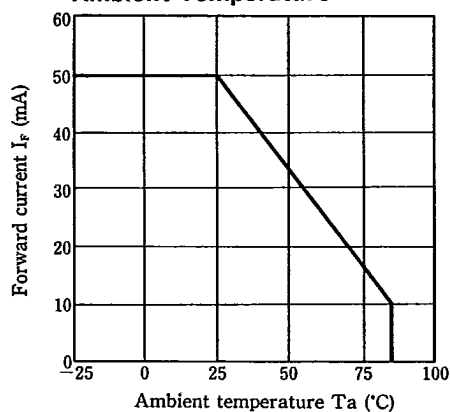


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

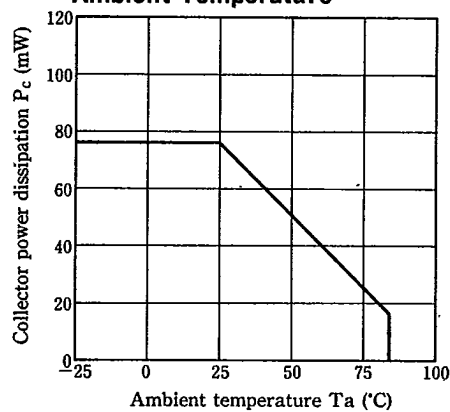


Fig. 3 Peak Forward Current vs. Duty Ratio

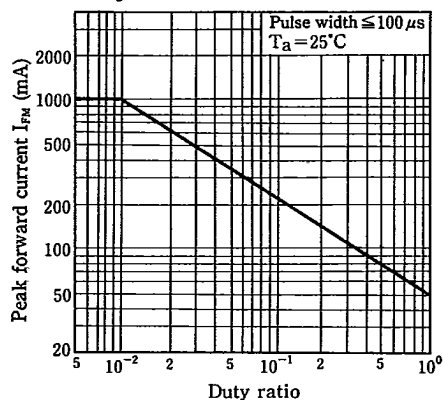
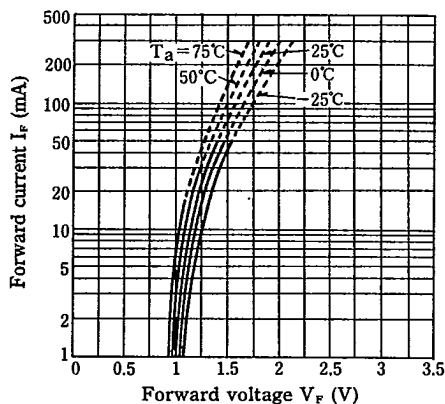


Fig. 4 Forward Current vs. Forward Voltage



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Fig. 5 Collector Current vs. Forward Current

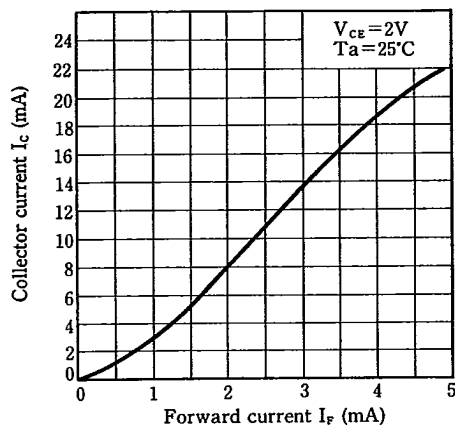


Fig. 6 Collector Current vs. Collector-emitter Voltage

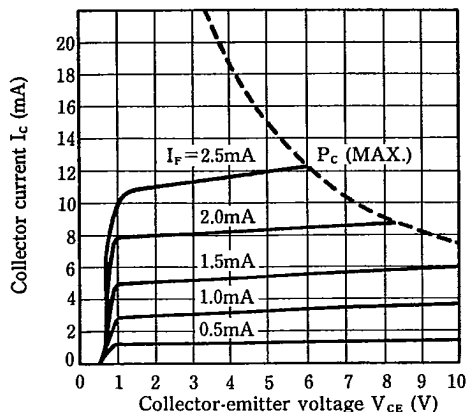


Fig. 7 Collector Current vs. Ambient Temperature

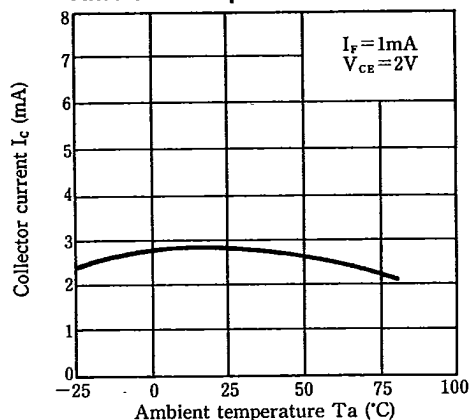


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

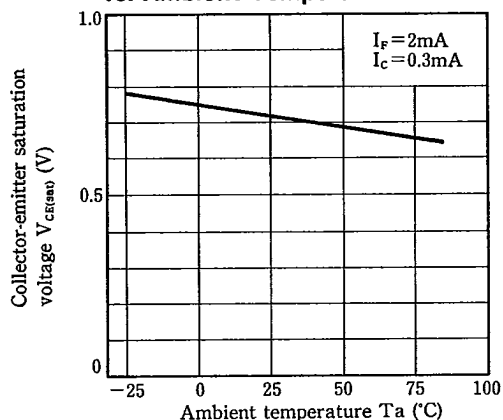
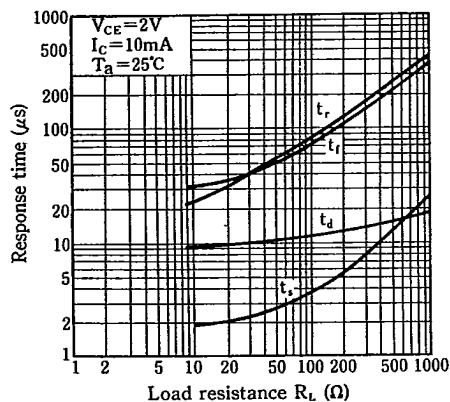
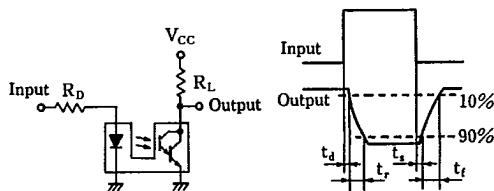


Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time



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Fig. 10 Frequency Response

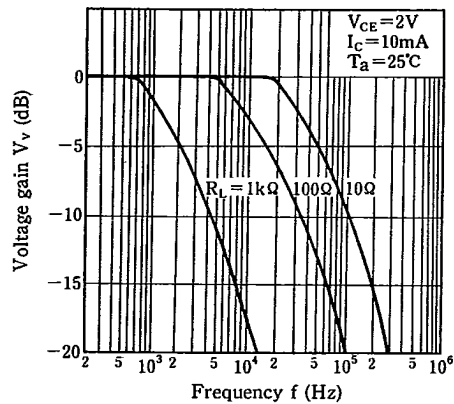


Fig. 11 Collector Dark Current vs. Ambient Temperature

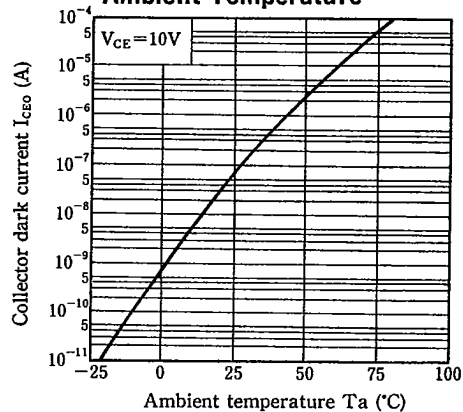


Fig. 12 Relative Collector Current vs. Shield Distance (1)

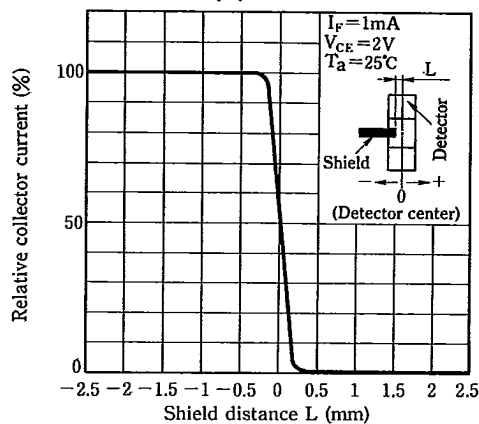
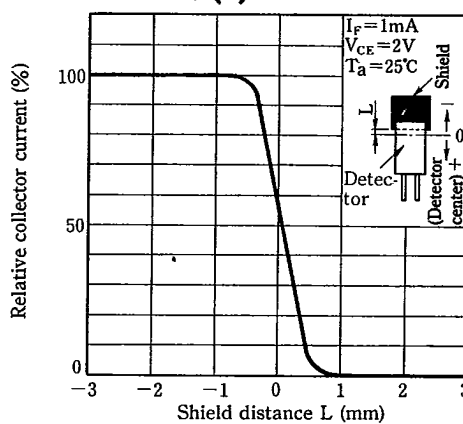


Fig. 13 Relative Collector Current vs. Shield Distance (2)



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